

BC63916

Switching and Amplifier Applications



1. Emitter 2. Collector 3. Base

NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings T_a=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{CER}	Collector-Emitter Voltage at R _{BE} =1KΩ	100	V
V _{CES}	Collector-Emitter Voltage	100	V
V _{CEO}	Collector-Emitter Voltage	80	V
V_{EBO}	Emitter-Base Voltage	5	V
I _C	Collector Current	1	А
P _C	Collector Power Dissipation	1	W
T _J , T _{STG}	Operating and Storage Junction Temperature Range	-55 ~ 150	°C

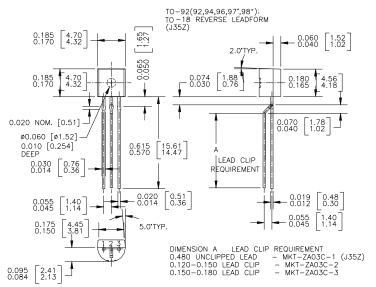
PW=5ms, Duty Cycle=10%

Electrical Characteristics T_a =25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
BV _{CBO}	Collector-Base Breakdown Voltage	$I_C = 100 \mu A, I_E = 0$	100			V
BV _{CEO}	Collector-Emitter Breakdown Voltage	$I_C = 10 \text{mA}, I_B = 0$	80			V
BV _{EBO}	Emitter-Base Breakdown Voltage	$I_E = 10\mu A, I_C = 0$	5.0			V
I _{CBO}	Collector Cut-off Current	$V_{CB} = 30V, I_{E} = 0$			100	nA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			10	μΑ
h _{FE1}	DC Current Gain	$V_{CE} = 2V$, $I_{C} = 5mA$	25			
h_{FE2}		$V_{CE} = 2V, I_{C} = 150mA$	100		250	
h_{FE3}		$V_{CE} = 2V, I_{C} = 500mA$	25			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	$I_C = 500 \text{mA}, I_B = 50 \text{mA}$			0.5	V
V _{BE} (on)	Base-Emitter On Voltage	$V_{CE} = 2V, I_{C} = 500 \text{mA}$			1	V
f _T	Current Gain Bandwidth Product	$V_{CE} = 5V$, $I_{C}=10$ mA, f = 50MHz		100		MHz

Package Dimensions

TO-92



Note: All package 97 or 98 transistors are leadformed to this configuration prior to bulk shipment. Order L34Z option if in-line leads are preferred on package 97 or 98.

Dimensions in Millimeters

^{*} Standard Option on 97 & 98 package code

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Programmable Ad	ctive Droop™	OPTOPLANAR™	SMART START™	

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